



**ANALOG
DEVICES**

10-Bit High-Speed Multiplying D/A Converter (Universal Digital Logic Interface)

ANALOG DEVICES INC

DAC-10

1.0 SCOPE

This specification covers the detail requirements for a 10-bit monolithic digital-to-analog converter which provides full-scale accuracy and high speed performance.

It is highly recommended that this data sheet be used as a baseline for new military or aerospace spec control drawings.

1.2 Part Number. The complete part numbers per Table I of this specification follow:

<u>Device</u>	<u>Part Number</u>	<u>Package</u>
B	DAC-10BX/883	X

1.2.3 Case Outline.

<u>Letter</u>	<u>Case Outline (Lead finish per MIL-M-38510)</u>
X	18-lead ceramic dual-in-line package (CERDIP)

1.3 Absolute Maximum Ratings. ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Operating Temperature Range	-55°C to $+125^\circ\text{C}$
DICE Junction Temperature Range (T_J)	-65°C to $+150^\circ\text{C}$
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Power Dissipation	500mW
Derate Above 100°C	10mW/ $^\circ\text{C}$
Lead Temperature (Soldering, 60 sec)	$+300^\circ\text{C}$
V+ Supply to V- Supply	36V
Logic Inputs	V- to (V- + 36V)
V_{LC}	V- to V+
Analog Current Outputs	+18V to -18V
Reference Inputs (V_{16} to V_{17})	V- to V+
Reference Input Differential Voltage (V_{16} to V_{17})	$\pm 18\text{V}$
Reference Input Current (I_{16})	2.5mA

1.5 Thermal Characteristics:

Thermal Resistance, CERDIP (X) package:

Junction-to-Case (θ_{JC}) = 35°C/W MAX

Junction-to-Ambient (θ_{JA}) = 120°C/W MAX

TABLE 1

$V_S = \pm 15V$; $I_{REF} = 2mA$; $-55^\circ C \leq T_A \leq +125^\circ C$ unless otherwise specified.

Output characteristics refer to both I_{OUT} and I_{OUT-} .

DAC-10/883					
Characteristics	Symbol	Special Conditions	LIMITS B		Units
			Min	Max	
Power Supply	I+	$V_S = \pm 15V$	—	4	mA
		$V_S = +5V, -7.5V$; $I_{REF} = 1mA$	—	4	mA
	I-	$V_S = \pm 15V$	—	-15	mA
		$V_S = +5V, -7.5V$; $I_{REF} = 1mA$	—	-9	mA
Full-Scale Current	I_{FR}	$V_{REF} = 10.000V$ $R_{16}, R_{17} = 5.000k\Omega$	3.960	4.032	mA
		$V_{REF} = 10.000V$ $R_{16}, R_{17} = 5.000k\Omega$ $T_A = +25^\circ C$	3.978	4.014	mA
Output Voltage Compliance	V_{OC}	Full-Scale Current Change < 1 LSB, $T_A = +25^\circ C$	-5	10	V
Power Supply Sensitivity	$PSSI_{FS+}$	$V+ = +4.5$ to $+18V$; $V- = -18V$	—	± 0.01	$\frac{\% \Delta I_{FS}}{\% \Delta V+}$
	$PSSI_{FS-}$	$V- = -10$ to $-18V$; $V+ = +18V$	—	± 0.01	$\frac{\% \Delta I_{FS}}{\% \Delta V-}$
Logic Input Levels	V_{IL}	Logic "0", $V_{LC} = 0V$	—	0.8	V
	V_{IH}	Logic "1", $V_{LC} = 0V$	2.0	—	V
Logic Input Current (Each Bit)	I_{IL}	$V_{IN} = -5V$, $V_{LC} = 0V$	—	-10	μA
	I_{IH}	$V_{IN} = 18V$, $V_{LC} = 0V$	—	10	μA
Zero-Scale Current	I_{ZS}		—	± 0.5	μA
Full-Scale Symmetry	I_{FSS}	$ I_{FR} - \overline{I_{FR}} $	—	4.0	μA
Monotonicity			10	—	Bits

TABLE 1 (Continued)

$V_S = \pm 15V$; $I_{REF} = 2mA$; $-55^\circ C \leq T_A \leq +125^\circ C$ unless otherwise specified.
Output characteristics refer to both I_{OUT} and I_{OUT-} .

Characteristics	Symbol	Special Conditions	DAC-10/883		Units
			LIMITS B		
			Min	Max	
Nonlinearity	NL		—	±1/2	LSB
Settling Time	t _s	All Bits Switched On or Off, Settle to 0.05% of FS T _A = +25°C	—	165	ns
Differential Nonlinearity	DNL		—	±1	LSB
Power Dissipation (Note 1)	P _d	V _S = ±15V	—	285	mW
		V _S = +5V, -7.5V; I _{REF} = 1mA	—	88	mW
Reference Bias Current	I _B		—	-3.0	μA

NOTES:

1. Power dissipation (P_d) limits are guaranteed by supply current testing.

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TABLE 2

DAC-10/883

Electrical Test Requirements For Class B Devices

MIL-STD-883 Test Requirements	Subgroups (see Table 3)
Interim Electrical Parameters (pre Burn-In)	1
Final Electrical Test Parameters	1*, 2, 3
Group A Test Requirements	1, 2, 3

* PDA applies to Subgroup 1 only.
No other Subgroups are included in PDA.

TABLE 3

Group A Inspection

$V_S = \pm 15V$; $I_{REF} = 2mA$ unless otherwise specified.
 Output characteristics refer to both I_{OUT} and I_{OUT} .

DAC-10/883					
Subgroup	Symbol	Special Conditions	LIMITS B		Units
			Min	Max	
Subgroup 1 $T_A = +25^\circ C$	I+	$V_S = \pm 15V$	—	4	mA
		$V_S = +5V, -7.5V$; $I_{REF} = 1mA$	—	4	mA
	I-	$V_S = \pm 15V$	—	-15	mA
		$V_S = +5V, -7.5V$; $I_{REF} = 1mA$	—	-9	mA
	I_{FR}	$V_{REF} = 10.000V$ $R_{16}, R_{17} = 5.000k\Omega$	3.978	4.014	mA
	V_{OC}	Full-Scale Current Change < 1 LSB	-5	10	V
	I_{ZS}		—	± 0.5	μA
	I_{FSS}	$ I_{FR} - \overline{I_{FR}} $	—	4	μA
	$PSSI_{FS+}$	$V+ = 4.5, 18V$ $V- = -18V$	—	± 0.01	$\frac{\% \Delta I_{FS}}{\% \Delta V+}$
	$PSSI_{FS-}$	$V- = -10, -18V$ $V+ = 18V$	—	± 0.01	$\frac{\% \Delta I_{FS}}{\% \Delta V-}$
	V_{IL}	Logic "0", $V_{LC} = 0V$	—	0.8	V
	V_{IH}	Logic "1", $V_{LC} = 0V$	2	—	V
	I_{IL}	$V_{IN} = -5V, V_{LC} = 0V$	—	-10	μA
	I_{IH}	$V_{IN} = +18V, V_{LC} = 0V$	—	10	μA
	Monotonicity		10	—	Bits
	NL		—	$\pm 1/2$	LSB

TABLE 3

Group A Inspection (Continued)

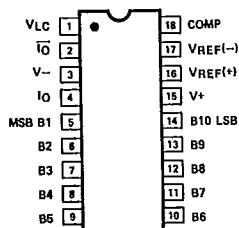
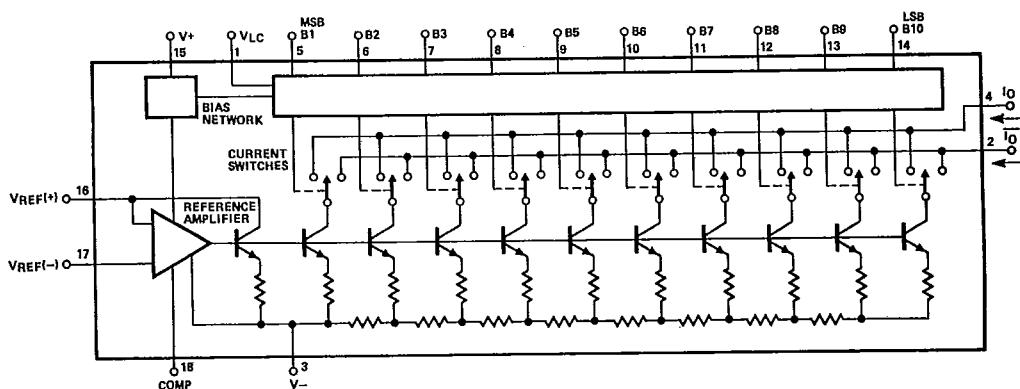
 $V_S = \pm 15V$; $I_{REF} = 2mA$ unless otherwise specified.Output characteristics refer to both I_{OUT} and I_{OUT} .

DAC-10/883					
Subgroup	Symbol	Special Conditions	<u>LIMITS B</u>		Units
			Min	Max	
Subgroup 1	DNL		—	± 1	LSB
$T_A = +25^\circ C$	I_B		—	-3.0	μA
(Continued)	P_d (Note 1)	$V_S = \pm 15V$	—	285	mW
		$V_S = +5V, -7.5V$; $I_{REF} = 1mA$	—	88	mW
Subgroup 2	I_{FR}	$V_{REF} = 10.000V$ $R_{16}, R_{17} = 5.000k\Omega$	3.960	4.032	mA
$T_A = +125^\circ C$		Remaining Tests, Limits and Conditions are the same as for Subgroup 1 excluding V_{OC} .			
Subgroup 3		All Tests, Limits and Conditions are the same as for Subgroup 2.			
$T_A = -55^\circ C$					

NOTES:

1. Power dissipation (P_d) limits are guaranteed by supply current testing.

3.2.1 Simplified Schematic and Pin Connections.



18-PIN HERMETIC DIP
(X-Suffix)

3.2.4 Microcircuit Group Assignment. This microcircuit is covered by microcircuit group 56.

4.2 Life Test/Burn-In Circuit.

